Data Sheet

SAM-980-4-1ps-x



SAM™ Data Sheet SAM-980-4-1ps-x, λ = 980 nm

Laser wavelength	$\lambda = 980 \text{ nm}$
High reflection band	λ = 910 990 nm
Saturable absorptance	$A_0 = 4 \%$
Modudation depth	ΔR = 2.4 %
Non-saturable loss	A _{ns} = 1.6 %
Saturation fluence	Φ_{sat} = 80 µJ/cm ²
Relaxation time constant	τ ~ 1ps
Damage threshold	Φ = 1.2 mJ/cm ²
Chip area	4.0 mm x 4.0 mm; other dimensions on request
Chip thickness	450 μm
Protection	the SAM is protected with a dielectric front layer
Mounting option x denotes the type of mounting as follows: x = 0 unmounted x = 12.7 g glued on a gold plated Cu-cylinder with 12.7 mm Ø	

ctor

Low intensity spectral reflectance

